

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1
 Stylesheet Version v1.2

EPAS ID: PAT3580622

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
NING ZHU	10/21/2015
DAMON G. HOLMES	10/21/2015
JEFFREY K. JONES	10/21/2015
RECEIVING PARTY DATA	
Name:	Freescall Semiconductor, Inc.
Street Address:	6501 William Cannon Drive West
Internal Address:	Law Department
City:	Austin
State/Country:	TEXAS
Postal Code:	78735
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	14919513
CORRESPONDENCE DATA	
Fax Number:	(512)895-6630
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
Phone:	512-895-6979
Email:	usadocketing@freescall.com
Correspondent Name:	FREESCALE SEMICONDUCTOR, INC.
Address Line 1:	6501 WILLIAM CANNON DRIVE WEST
Address Line 2:	TX30/OE62
Address Line 4:	AUSTIN, TEXAS 78735
ATTORNEY DOCKET NUMBER:	RF50155RC
NAME OF SUBMITTER:	SHANNON WILLIAMS
SIGNATURE:	/Shannon Williams/
DATE SIGNED:	10/21/2015
Total Attachments: 4	
source=RF50155RC-US-Assignment#page1.tif	
source=RF50155RC-US-Assignment#page2.tif	

source=RF50155RC-US-Assignment#page3.tif

source=RF50155RC-US-Assignment#page4.tif

ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **ZHU, Ning, an individual; HOLMES, Damon G., an individual; and JONES, Jeffrey K., an individual;** have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, State of Texas, United States of America, and its successors, assigns, and legal representatives, the entire right, title and interest for the United States of America in and to certain inventions relating to improvements in **RF POWER TRANSISTORS WITH IMPEDANCE MATCHING CIRCUITS, AND METHODS OF MANUFACTURE THEREOF** (Docket No. **RF50155RC**), described, illustrated and claimed in an application for Letters Patent of the United States of America executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.**, for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to **FREESCALE SEMICONDUCTOR, INC.**

We agree that, when requested, we will, without charge to **FREESCALE SEMICONDUCTOR, INC.**, but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives or nominees.

RF50155RC

We covenant with FREESCALE SEMICONDUCTOR, INC., its successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.



ZHU, Ning

DATE: 10/21/2015

First Witness



SIGNATURE OF WITNESS

DATE: 10/21/2015
(Month-Day-Year)

Lei Zhao

PRINTED NAME OF WITNESS

945 E. Prescott PL, Chandler, AZ 85249

PRINTED ADDRESS OF WITNESS

Second Witness



SIGNATURE OF WITNESS

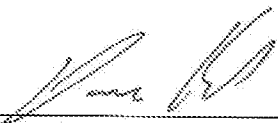
DATE: 10/21/2015
(Month-Day-Year)

Xin Fu

PRINTED NAME OF WITNESS

800 W Willis Rd #7066, Chandler, AZ, 85286

PRINTED ADDRESS OF WITNESS


HOLMES, Damon G.

DATE: Oct. 21, 2015

First Witness


SIGNATURE OF WITNESS

DATE: 10-21-15
(Month-Day-Year)

Elie A. Maalouf
PRINTED NAME OF WITNESS

3538 E. Fox St Mesa, AZ 85213
PRINTED ADDRESS OF WITNESS

Second Witness


SIGNATURE OF WITNESS

DATE: 10-21-2015
(Month-Day-Year)

Humayun Kabir
PRINTED NAME OF WITNESS

3289 E Magnolia Dr, Gilbert AZ 85298
PRINTED ADDRESS OF WITNESS

Jeffrey K. Jones
JONES Jeffrey K.

DATE: OCT. 21, 2015

First Witness

Elie A. Maalouf
SIGNATURE OF WITNESS

DATE: 10-21-15
(Month-Day-Year)

Elie A. Maalouf
PRINTED NAME OF WITNESS

3538 E. Fox St Mesa, AZ 85213
PRINTED ADDRESS OF WITNESS

Second Witness

Humayun Kabir
SIGNATURE OF WITNESS

DATE: 10-21-2015
(Month-Day-Year)

Humayun Kabir
PRINTED NAME OF WITNESS

3289 E Magnolia Dr. Gilbert AZ 85298
PRINTED ADDRESS OF WITNESS

RF50155RC